| Ref # | Hits | Search Query | DBs | Default Operat or | Plural s | Time Stamp |
|----------|------|--|--|-------------------------|-------------|---------------------|
| L1 | 0 | ("(gatewithdielectric)and(diffe rentwiththickness)and(ONO)").PN. | US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB | OR | OFF | 2005/04/20 10:36 |
| L2 | 494 | (gate with dielectric) and (different with thickness) and (ONO) | US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB | OR | ON | 2005/04/20 10:38 |
| L3 | 236 | (gate with dielectric) and (different with thickness) and (ONO) and (second with nitride) | US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB | OR | ON | 2005/04/20 10:39 |
| L4 | 82 | (gate with dielectric) and (different with thickness) and (ONO) and (second with nitride) and (third with oxide) | US-PGPU B; USPAT; EPO; JPO; DERWEN T; IBM_TDB | OR | ON | 2005/04/20 10:39 |